



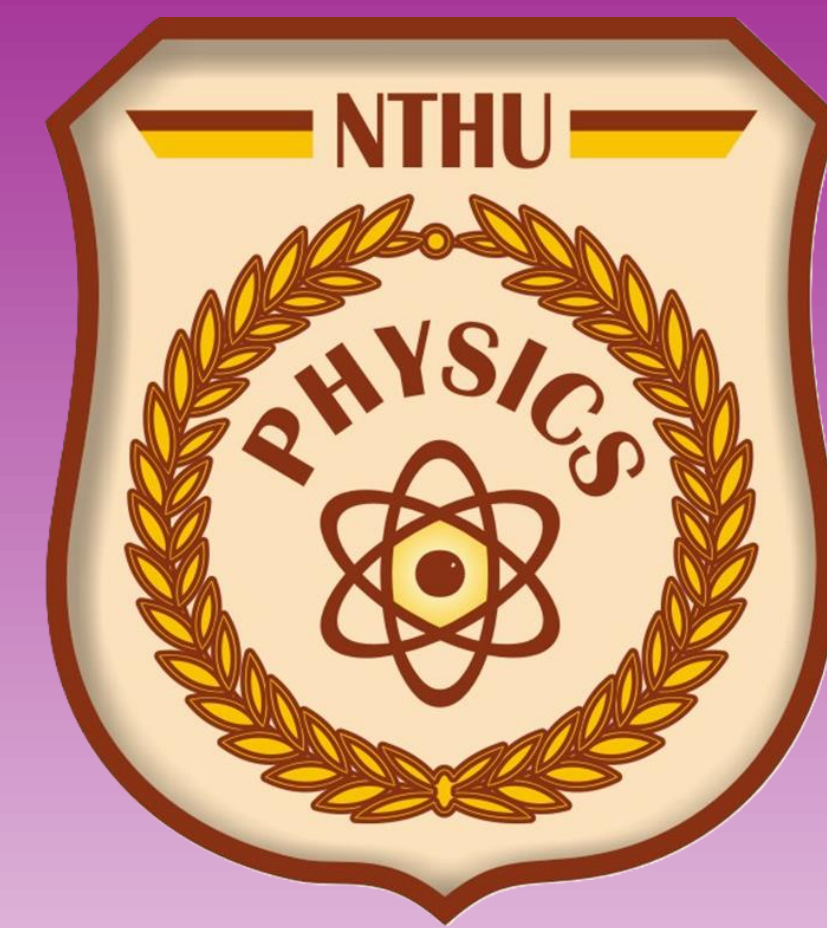
High-quality blue quantum emitters in hexagonal boron nitride without background fluorescence.

Ming-Hao Guo^{1*}, Tzu-Chieh Chou^{1,2}, Ro-Ya Liu², Wei-Ting Hsu^{1,2}

¹Department of Physics, National Tsing Hua University, Hsinchu 300044, Taiwan

²National Synchrotron Radiation Research Center, Hsinchu 30076, Taiwan

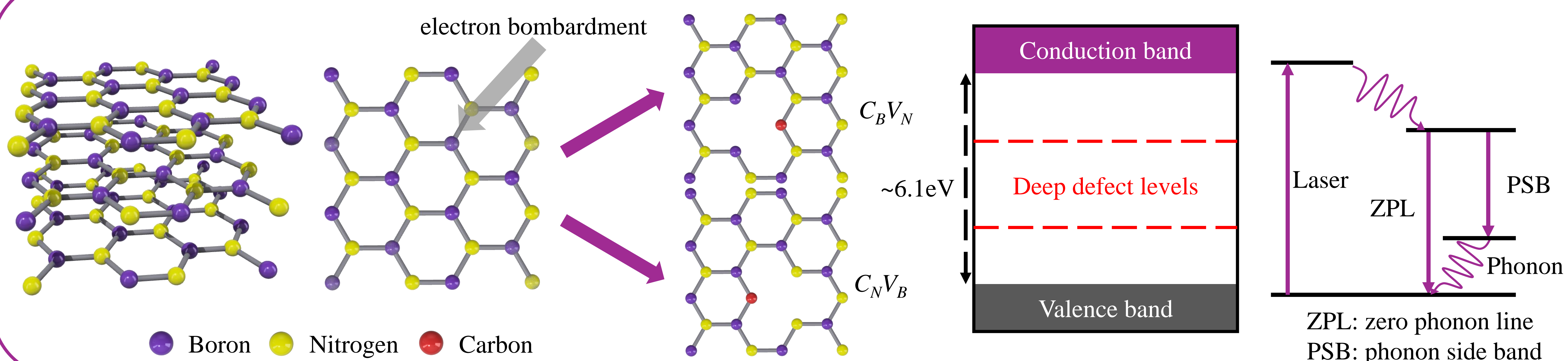
* Presenter: Ming-Hao Guo, email:howard2001kao@gmail.com



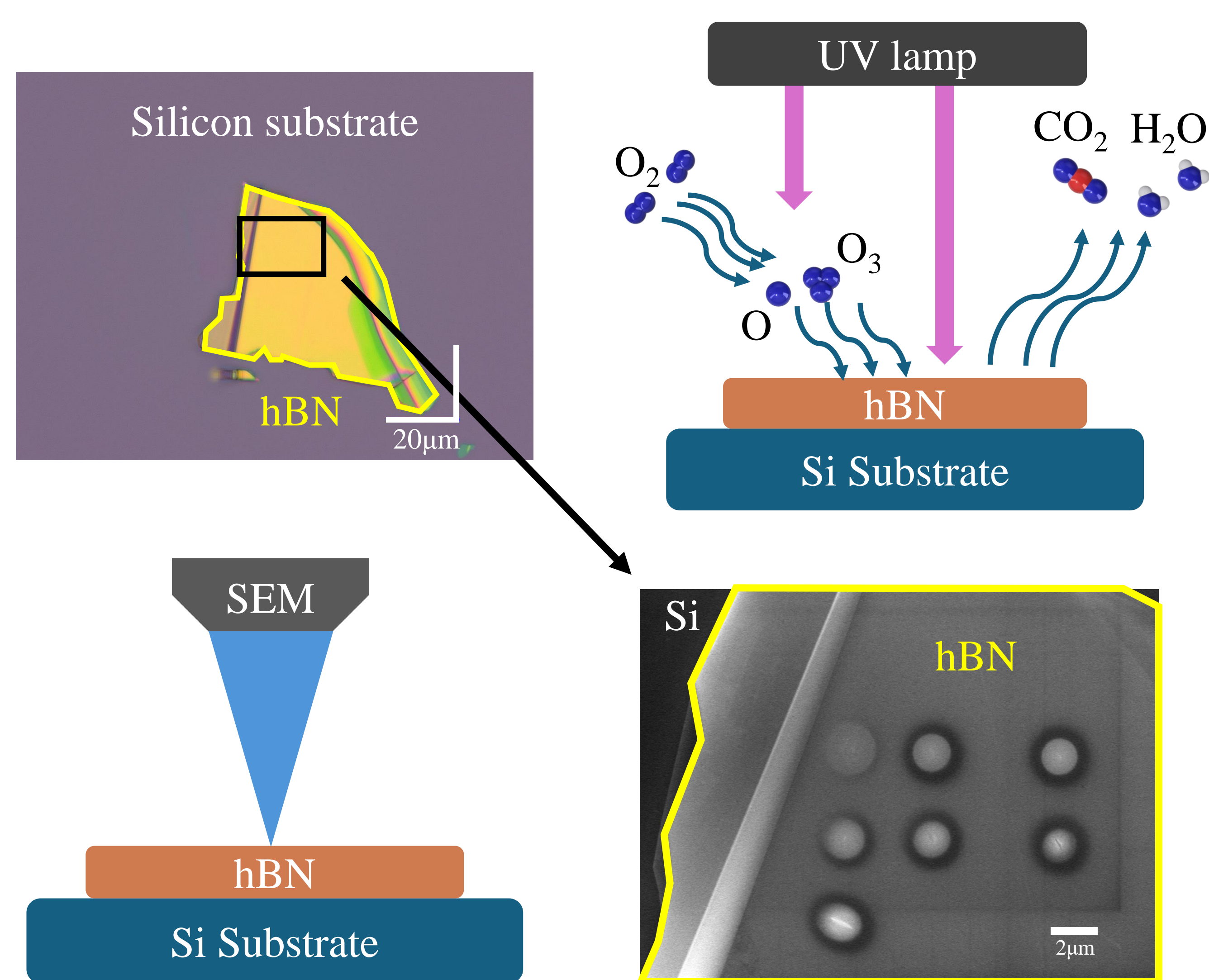
Abstract

Single-photon sources in wide-band gap hexagonal boron nitride (hBN) hold great promise for applications in quantum communication and quantum key distribution. However, the production of high-quality quantum light sources in hBN remains a challenge. In this work, we focus on fabricating blue quantum emitters (near 436 nm) via electron bombardment, combined with thermal annealing and plasma treatment to effectively eliminate background fluorescence. By removing surface contaminants that previously caused spectral interference, we achieve stable and clean quantum dots. Polarization-resolved photoluminescence measurements further demonstrate excellent crystal alignment. Our findings are crucial for advancing defect engineering and practical applications of quantum optical technologies.

Introduction

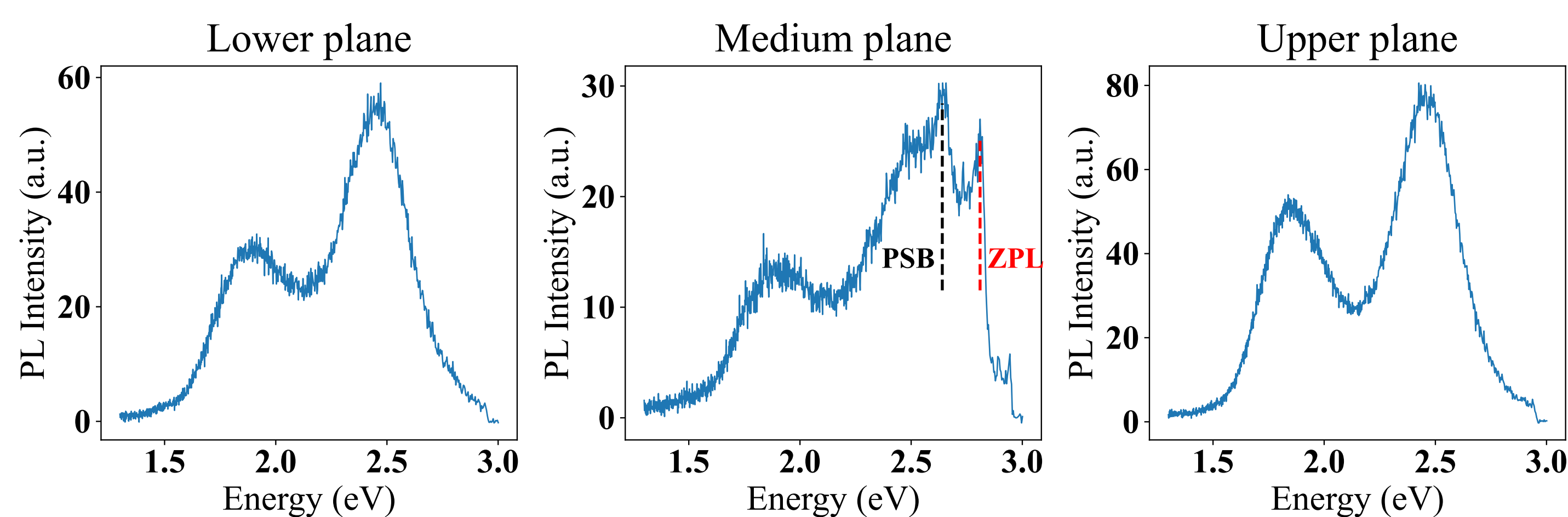


Sample Preparation

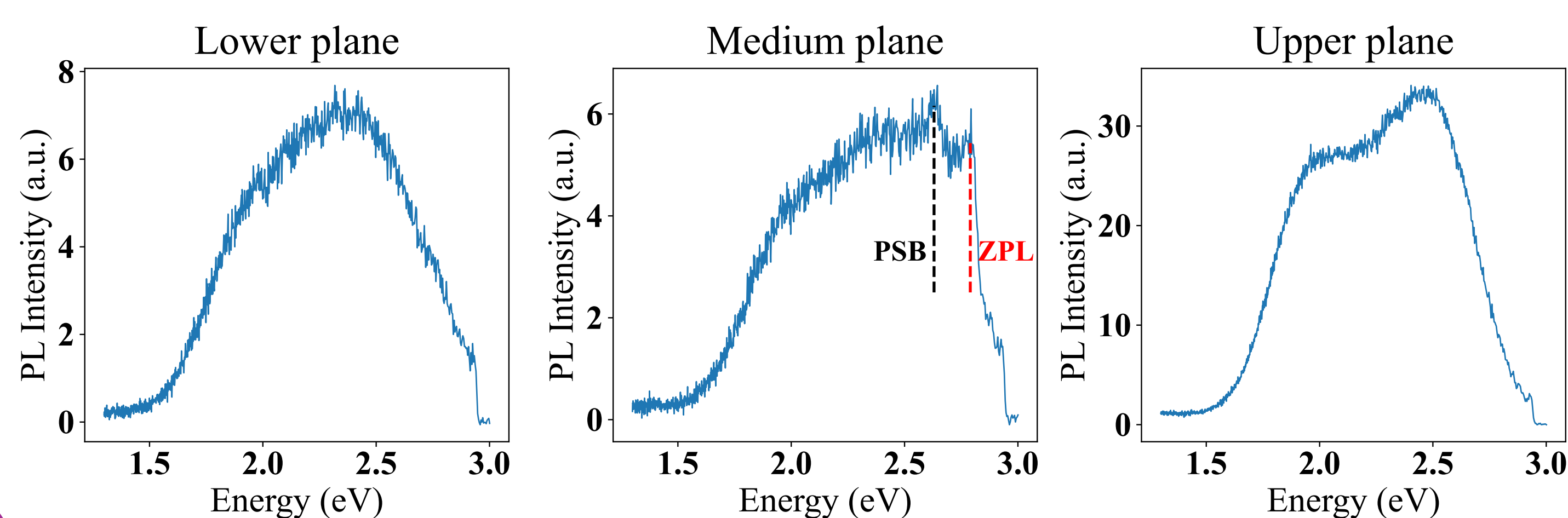


Vacuum Anneal

Before vacuum anneal

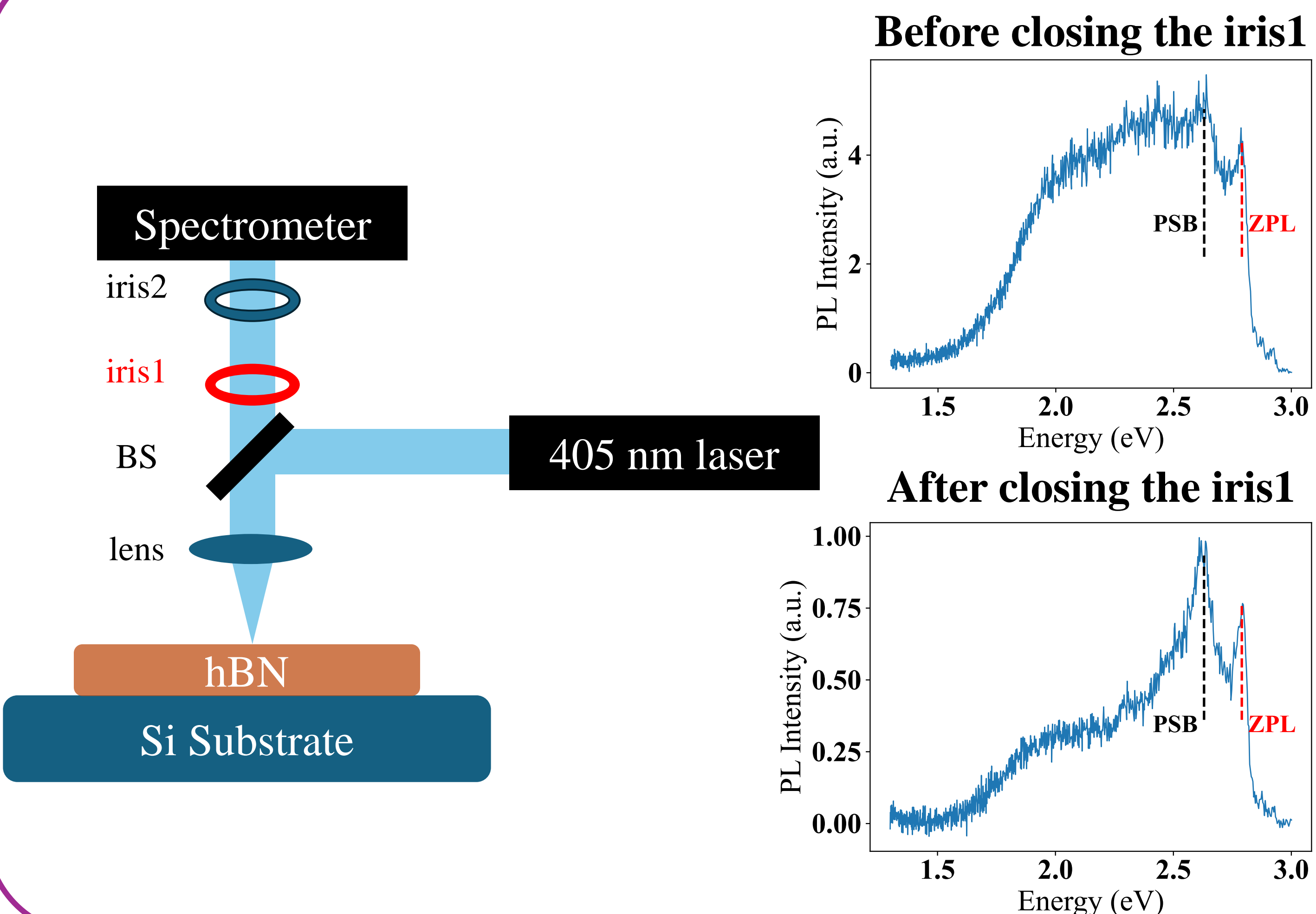


After vacuum anneal



400 °C
~ 3×10^{-2} Torr
2 hr

Multi-direction Background Fluorescence



Conclusion

- 1) After 400°C vacuum annealing for 2 hours, a portion of the background fluorescence disappeared.
- 2) A portion of background fluorescence seems not to follow the same path with blue quantum emitter.

Reference and Acknowledgement

This research was supported by the National Science and Technology Council of Taiwan (Grants 111-2112-M-213-010-MY3 and 112-2112-M-007-036-MY3) and the Yushan Fellow Program from the Ministry of Education of Taiwan (Grant MOE-109-YSFMS-0002-001-P1).

Nedić, S., Yamamura, K., Gale, A., Aharonovich, I., & Toth, M. (2024). Electron beam restructuring of quantum emitters in hexagonal boron nitride. *Advanced Optical Materials*, 12(24). <https://doi.org/10.1002/adom.202400908>